## 3 Watt Cellular T/R and Antenna Changeover Switch

## Features

- Low Insertion Loss: < 0.4 dB @ 1900 MHz
- Low Current Consumption: $<20 \mu \mathrm{~A} @+5 \mathrm{~V}$
- High Intercept Point: 58 dBm @ 1 GHz
- Positive or Negative Voltage Control
- CDMA, W-CDMA, TDMA, GSM, PCS and DCS
- Lead-Free Plastic SOT-26 Package
- $100 \%$ Matte Tin Plating over Copper
- Halogen-Free "Green" Mold Compound
- $260^{\circ} \mathrm{C}$ Reflow Compatible
- RoHS* Compliant Version of SW-425


## Description

M/A-COM's MASWSS0143 is a GaAs monolithic switch in a lead-free, SOT-26 surface mount plastic package. The MASWSS0143 is ideally suited for applications where very low power consumption, low intermodulation products and very small size are required.

Typical applications include internal / external antenna select switch for portable telephones and data radios. In addition because of its low loss, good isolation, and inherent speed, the MASWSS0143 can be used as a conventional T/R switch or as an antenna diversity switch.

The MASWSS0143 can be used in power applications up to 3 watts in systems such as cellular PCS, CDMA, W-CDMA, TDMA, GSM and other analog / digital wireless communications systems.

The MASWSS0143 is fabricated using a 0.5 micron gate length GaAs PHEMT process. The process features full chip passivation for increased performance and reliability.

## Ordering Information ${ }^{1}$

| Part Number | Package |
| :---: | :---: |
| MASWSS0143 | Bulk Packaging |
| MASWSS0143TR | 1000 piece reel |
| MASWSS0143TR-3000 | 3000 piece reel |

[^0]
## Functional Block Diagram



## Pin Configuration

| Pin No. | Function | Description |
| :---: | :---: | :---: |
| 1 | RF1 | RF In/Out |
| 2 | GND | RF Ground |
| 3 | RF2 | RF In/Out |
| 4 | VB | Voltage Control B |
| 5 | RFC | RF Common |
| 6 | VA | Voltage Control A |

Absolute Maximum Ratings ${ }^{2,3}$

| Parameter | Absolute Maximum |
| :---: | :---: |
| Input Power (1 GHz) | +36 dBm |
| V Control | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Operating Temperature | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Storage Temperature |  |

2. Exceeding any one or combination of these limits may cause permanent damage to this device.
3. $M / A-C O M$ does not recommend sustained operation near these survivability limits.
[^1]3 Watt Cellular T/R and Antenna Changeover Switch DC-3.0 GHz

Electrical Specifications: $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CTL}}=0 / 5 \mathrm{~V}, \operatorname{Pin}=30 \mathrm{dBm}, \mathrm{Z}_{0}=50 \Omega^{4}$

| Parameters | Test Conditions | Units | Min. | Tур. | Max. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Insertion Loss | $\begin{gathered} \mathrm{DC}-1 \mathrm{GHz} \\ 1-2 \mathrm{GHz} \\ 2-3 \mathrm{GHz} \end{gathered}$ | dB <br> dB <br> dB | - | $\begin{aligned} & 0.35 \\ & 0.40 \\ & 0.65 \end{aligned}$ | $\begin{gathered} 0.50 \\ - \end{gathered}$ |
| Isolation | $\begin{gathered} \mathrm{DC}-1 \mathrm{GHz} \\ 1-2 \mathrm{GHz} \\ 2-3 \mathrm{GHz} \end{gathered}$ | $\begin{aligned} & \mathrm{dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \end{aligned}$ | 18 - | $\begin{aligned} & 22 \\ & 16 \\ & 11 \end{aligned}$ | - |
| VSWR | DC-3 GHz | Ratio | - | 1.2:1 | - |
| P1dB | 1 GHz | dBm | - | 36 | - |
| IP2 | 2-Tone, 5 MHz Spacing, 1 GHz Pin $=+10 \mathrm{dBm} /$ Tone | dBm | - | 110 | - |
| IP3 | 2-Tone, 5 MHz Spacing, 1 GHz Pin $=+10 \mathrm{dBm} /$ Tone | dBm | - | 58 | - |
| 2nd Harmonics | Pin $=+30 \mathrm{dBm}, \mathrm{f}_{0}=1 \mathrm{GHz}$ | dBc | - | -78 | - |
| 3rd Harmonics | Pin $=+30 \mathrm{dBm}, \mathrm{f}_{0}=1 \mathrm{GHz}$ | dBc | - | -82 | -70 |
| Trise, Tfall | 10\% to 90\% RF, 90\% to 10\% RF | nS | - | 60 | - |
| Ton, Toff | 50\% control to 90\% RF, 50\% control to 10\% RF | nS | - | 20 | - |
| Transients |  | mV | - | 20 | - |
| Control Current | $\mathrm{V}_{\text {CTL }}=5 \mathrm{~V}$ | $\mu \mathrm{A}$ | - | 5 | 20 |

4. For positive voltage control, external DC blocking capacitors are required on all RF ports.

## Truth Table ${ }^{5,6}$

| Control A | Control B | RFC - RF1 | RFC - RF2 |
| :---: | :---: | :---: | :---: |
| 0 | 1 | Off | On |
| 1 | 0 | On | Off |

5. Differential voltage, V (state 1$)-\mathrm{V}$ (state 0 ), must be +2.5 V minimum and must not exceed 8 V .
6. $0=-8 \mathrm{~V}$ to $0 \mathrm{~V}, 1=-5.5 \mathrm{~V}$ to 8.0 V

## Handling Procedures

Please observe the following precautions to avoid damage:

## Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Lead-Free SOT-26 ${ }^{\dagger}$


NOTES: 1. REFERENCE JEDEC MO-178-AB FOR ADDITIONAL DIMENSIONAL AND TOLERANCE INFORMATION. 2. REFERENCE M538 APPLICATION NOTE FOR PCB FOOTPRINT INFORMATION.
3. ALL DIMENSIONS SHOWN AS INCHES/MM.
${ }^{\dagger}$ Reference Application Note M538 for lead-free solder reflow recommendations.

- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298

Visit www.macom.com for additional data sheets and product information.

## Typical Performance Curves

Insertion Loss, 1000 pF


Isolation, 1000 pF


VSWR, 1000 pF


Insertion Loss, 39 pF


Isolation, 39 pF


VSWR, 39 pF


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[^0]:    1. Reference Application Note M513 for reel size information.
[^1]:    * Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

